

2n60 inverter



2n60 inverter



2 Amps, 600 Volts

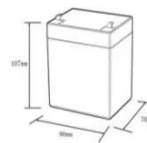
The 2N60 is a high voltage MOSFET and is designed to have better characteristics, such as fast switching time, low gate charge, low on-state resistance and have a high rugged avalanche ...

[Learn More](#)

2A, 600V N-CHANNEL POWER MOSFET

DESCRIPTION The UTC 2N60 is a high voltage power MOSFET and is designed to have better characteristics, such as fast switching time, low gate charge, low on-state resistance and have a high ...

[Learn More](#)



12.8V6Ah	
Nominal voltage (V):	12.8
Nominal capacity (Ah):	6
Rated energy (WH):	76.8
Maximum charging voltage (V):	14.6
Maximum charging current (A):	6
Floating charge voltage (V):	13.6-13.8
Maximum continuous discharge current (A):	10
Maximum peak discharge current @10 seconds (A):	20
Maximum load power (W):	100
Discharge cut-off voltage (V):	10.8
Charging temperature (°C):	-50
Discharge temperature (°C):	-20-+60
Working humidity:	<95% R.H (non condensing)
Number of cycles (25 °C, 0.5c, 100%doD):	>2000
Cell combination mode:	32700-4s1p
Terminal specification:	T2 (6.3mm)
Protection grade:	IP65
Overall dimension (mm):	50*70*107mm
Reference weight (kg):	0.7
Certification:	un38.3/msds



2N60 Datasheet: MOSFET, N-Ch, 600V, 2A. Full specification with ...

2N60 Datasheet: MOSFET/N-Ch/600V/2A. View the complete specification and find equivalents, replacement transistors, pin configuration.

[Learn More](#)

2N60 Datasheet, PDF

The 2N60 is an N-Channel MOSFET that is optimized for high voltage power applications, offering features such as fast switching, low gate charge, and low on-state resistance. It is also designed to

...

[Learn More](#)



UNISONIC TECHNOLOGIES CO., LTD

The UTC 2N60 is a high voltage power MOSFET and is designed to have better characteristics, such as fast switching time, low gate charge, low on-state resistance and have a high rugged avalanche ...

[Learn More](#)

2N60 N-Channel Power MOSFET Specs , PDF

This document describes the 2N60 power MOSFET, which is designed for high-speed switching applications. It has characteristics suitable for uses like power supplies, motor controls, and DC-DC ...

[Learn More](#)



DFF2N60 Datasheet - 600V, 2.4A, N-Ch, MOSFET, Transistor

Function: 600V, 2.4A, N-Channel MOSFET. Package: TO-220 / TO-220F. Manufacturer: Discrete & Integration

Semiconductor. Image and Pinouts: The DFF2N60 is 600V, 2.4A, High ...

[Learn More](#)



2N60 PDF Datasheet - 2A, 600V, N-Ch, MOSFET, Transistor

The UTC 2N60 is a high voltage MOSFET and is designed to have better characteristics, such as fast switching time, low gate charge, low on-state resistance and have a high rugged ...

[Learn More](#)



2N60 Datasheet (PDF)

The UTC 2N60 is a high voltage power MOSFET and is designed to have ...

[Learn More](#)



2N60 Datasheet (PDF)

The UTC 2N60 is a high voltage power MOSFET and is designed to have better characteristics, such as fast switching time, low gate charge, low on-state resistance and have a high rugged

avalanche ...

[Learn More](#)



Contact Us

For catalog requests, pricing, or partnerships, please visit:
<https://www.v4venison.co.za>

